

LATCH (LATCHING) TYPE HEAT-DRIVEN MICRORELAY DEVICE (09-161640)
Publication Number: JP 9161640 A , June 20, 1997

Inventors:

- BUUTYAN CHIYOI
- KIYUNHO PAAKU
- JIYONHIYUN RII
- HIYUNJIYON YUU

Applicants

- KANKOKU DENSHI TSUSHIN KENKYUSHO (A Non-Japanese Company or Corporation), KR (Korea) Republic of

Application Number: 08-163401 (JP 96163401) , June 24, 1996

Priority:

- 9549249 [KR 9549249], KR (Korea) Republic of, December 13, 1995

International Class (IPC Edition 6):

- H01H-061/00
- H01H-029/00
- H01H-061/01

JAPIO Class:

- 42.1 (ELECTRONICS--- Electronic Components)

JAPIO

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Dialog® File Number 347 Accession Number 5546840

Heat drive type micro relay element - has liquid metal provided at inside of channel and establishes contact between first/second signal electrode pairs

Patent Assignee: ZH KANKOKU DENSHI TSUSHIN KENKYUSHO; KOREA ELECTRONICS & TELECOM RES INST; KOREA ELECTRONICS & TELECOM RES

Inventors: CHOE B; LEE J; PARK K; YU H; CHOI B Y; LEE J H; PARK G H; YOO H J

Patent Family

| Patent Number | Kind | Date | Application Number | Kind | Date | Week | Type |
|---------------|------|----------|--------------------|------|----------|--------|------|
| JP 9161640 | A | 19970620 | JP 96163401 | A | 19960624 | 199735 | B |
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Priority Applications (Number Kind Date): KR 9549249 A (19951213)

Patent Details

| Patent | Kind | Language | Page | Main IPC | Filing Notes |
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| JP 9161640 | A | | 10 | H01H-061/00 | |
| KR 97054597 | A | | | H01L-043/00 | |
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| KR 174871 | B1 | | | H01L-043/00 | |

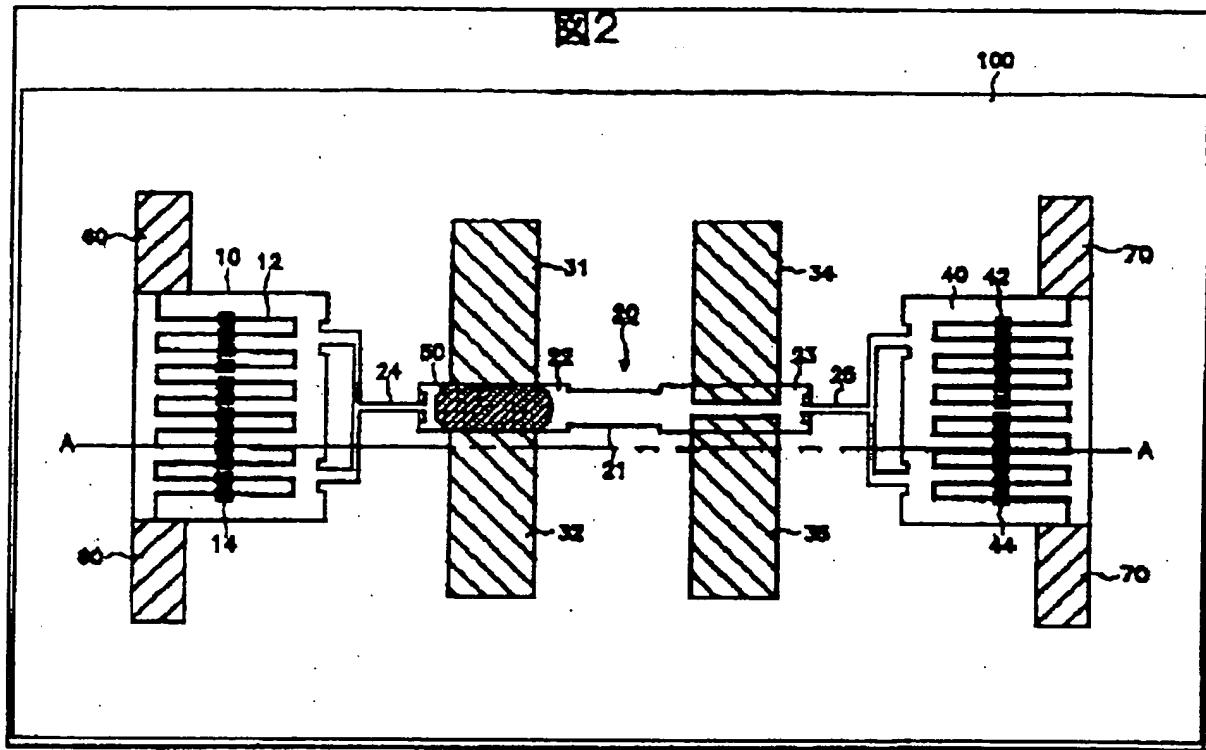
Abstract:

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The relay element has an active storage unit (10) and a passive storage unit (40) having same volume and which are arranged at predetermined intervals on a semiconductor substrate (100). A first heater (12) which heats the internal air and a second heater (42) are provided in the active and passive storage units respectively. A channel (20) which extends in the space between the active and passive storage units, serves as liquid metal shifting path. A pair of first signal electrodes (31,32) are mutually isolated.

One end of the first signal electrodes are inserted inside the predetermined area of the channel and other end extends outside. A pair of second signal electrodes (34,35) which are isolated are arranged similar to shaft of the first electrode pair. Liquid metal (50) provided at inside of the channel establishes contact between the first and the second electrode pair. A pair of glass substrates (120,130) are attached to the top and bottom side faces of the semiconductor substrate.

ADVANTAGE - Enables size reduction.



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